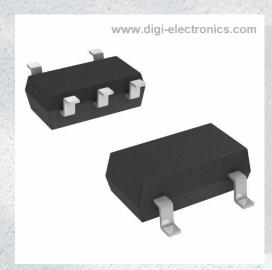


# **NLVVHC1G08DFT1G Datasheet**



https://www.DiGi-Electronics.com

DiGi Electronics Part Number NLVVHC1G08DFT1G-DG

Manufacturer onsemi

Manufacturer Product Number NLVVHC1G08DFT1G

Description IC GATE AND 1CH 2-INP SC88A

Detailed Description AND Gate IC 1 Channel SC-88A (SC-70-5/SOT-353)



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
NLVVHC1G08DFT1G	onsemi
Series:	Product Status:
74VHC	Obsolete
Logic Type:	Number of Circuits:
AND Gate	1
Number of Inputs:	Features:
2	
Voltage - Supply:	Current - Quiescent (Max):
2V ~ 5.5V	1 μΑ
Current - Output High, Low:	Input Logic Level - Low:
8mA, 8mA	0.5V ~ 1.65V
Input Logic Level - High:	Max Propagation Delay @ V, Max CL:
1.5V ~ 3.85V	7.9ns @ 5V, 50pF
Operating Temperature:	Grade:
-55°C ~ 125°C	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Supplier Device Package:	Package / Case:
SC-88A (SC-70-5/SOT-353)	5-TSSOP, SC-70-5, SOT-353
Base Product Number:	
NLVVHC1G08	

# **Environmental & Export classification**

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

www.onsemi.com

# Single 2-Input AND Gate

# MC74VHC1G08, MC74VHC1GT08

The MC74VHC1G08 / MC74VHC1GT08 is a single 2 input AND gate in tiny footprint packages. The MC74VHC1G08 has CMOS-level input thresholds while the MC74VHC1GT08 has TTL-level input thresholds.

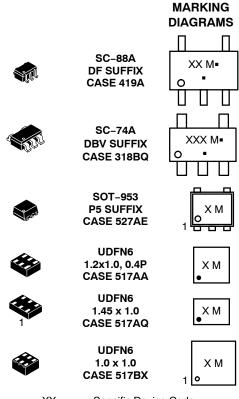
The input structures provide protection when voltages up to  $5.5~\rm V$  are applied, regardless of the supply voltage. This allows the device to be used to interface  $5~\rm V$  circuits to  $3~\rm V$  circuits. Some output structures also provide protection when  $\rm V_{CC}=0~\rm V$  and when the output voltage exceeds  $\rm V_{CC}$ . These input and output structures help prevent device destruction caused by supply voltage – input/output voltage mismatch, battery backup, hot insertion, etc.

#### **Features**

- Designed for 2.0 V to 5.5 V V<sub>CC</sub> Operation
- 3.5 ns t<sub>PD</sub> at 5 V (typ)
- Inputs/Outputs Over-Voltage Tolerant up to 5.5 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 8 mA at 3.0 V
- Available in SC-88A, SC-74A, SOT-953 and UDFN6 Packages
- Chip Complexity < 100 FETs
- –Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Figure 1. Logic Symbol



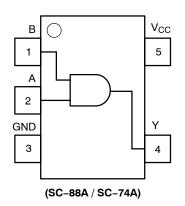
XX = Specific Device Code
M = Date Code\*
• Pb-Free Package

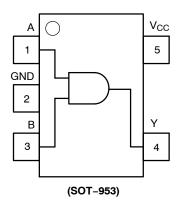
(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 7 of this data sheet.

<sup>\*</sup>Date Code orientation and/or position may vary depending upon manufacturing location.





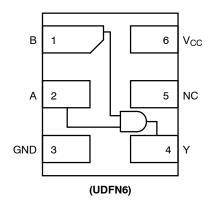


Figure 2. Pinout (Top View)

# **PIN ASSIGNMENT**

(SC-88A / SC-74A)

Pin	Function
1	В
2	А
3	GND
4	Y
5	V <sub>CC</sub>

# PIN ASSIGNMENT (SOT-953)

Pin	Function
1	Α
2	GND
3	В
4	Y
5	V <sub>CC</sub>

# PIN ASSIGNMENT (UDFN)

Pin	Function
1	В
2	Α
3	GND
4	Y
5	NC
6	V <sub>CC</sub>

# **FUNCTION TABLE**

Inp	Output	
Α	В	Υ
L	L	L
L	Н	L
Н	L	L
Н	Н	Н

### **MAXIMUM RATINGS**

Symbol	Characteristics		Value	Unit
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +6.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +6.5	V
V <sub>OUT</sub>	Tri–	(High or Low State) State Mode (Note 1) n Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
l <sub>ok</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Ground Pin		±50	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 secs		260	°C
TJ	Junction Temperature Under Bias		+150	°C
θЈА	Thermal Resistance (Note 2)	SC-88A SC-74A SOT-553 SOT-953 UDFN6	377 320 324 254 154	°C/W
P <sub>D</sub>	Power Dissipation in Still Air	SC-88A SC-74A SOT-553 SOT-953 UDFN6	332 390 386 491 812	mW
MSL	Moisture Sensitivity		Level 1	-
F <sub>R</sub>	Flammability Rating Ox	ygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V <sub>ESD</sub>		Human Body Model arged Device Model	2000 1000	V
I <sub>Latchup</sub>	Latchup Performance (Note 4)		± 100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Applicable to devices with outputs that may be tri-stated.
   Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
   HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
- 4. Tested to EIA/JESD78 Class II.

# **RECOMMENDED OPERATING CONDITIONS**

Symbol	Ch	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage		2.0	5.5	V
V <sub>IN</sub>	DC Input Voltage		0	5.5	V
V <sub>OUT</sub>	DC Output Voltage	Active–Mode (High or Low State) Tri–State Mode (Note 1) Power–Down Mode ( $V_{CC} = 0 V$ )	0 0 0	V <sub>CC</sub> 5.5 5.5	٧
T <sub>A</sub>	Operating Temperature Range		-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time	$\begin{array}{c} V_{CC} = 2.0 \text{ V} \\ V_{CC} = 2.3 \text{ V to } 2.7 \text{ V} \\ V_{CC} = 3.0 \text{ V to } 3.6 \text{ V} \\ V_{CC} = 4.5 \text{ V to } 5.5 \text{ V} \end{array}$	0 0 0	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# DC ELECTRICAL CHARACTERISTICS (MC74VHC1G08)

		Test	V <sub>CC</sub>	٦	Γ <sub>A</sub> = 25°	C	-40°C ≤	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit	
$V_{IH}$	High-Level Input		2.0	1.5	-	-	1.5	-	1.5	-	V
	Voltage		3.0	2.1	-	-	2.1	-	2.1	-	
			4.5	3.15	-	-	3.15	-	3.15	-	
			5.5	3.85	-	-	3.85	-	3.85	-	
$V_{IL}$	Low-Level Input		2.0	-	-	0.5	-	0.5	-	0.5	V
	Voltage		3.0	-	-	0.9	-	0.9	-	0.9	
			4.5	-	-	1.35	-	1.35	-	1.35	
			5.5	-	-	1.65	-	1.65	-	1.65	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -4 \text{ mA} \\ &I_{OH} = -8 \text{ mA} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 –		1.9 2.9 4.4 2.48 3.80	- - - -	1.9 2.9 4.4 2.34 3.66	- - - -	V
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 50  \mu\text{A} \\ &I_{OL} = 4 \text{ mA} \\ &I_{OL} = 8 \text{ mA} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	_	_	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0.0	_	_	1.0	-	10	_	10	μА
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	_	1.0	-	20	_	40	μΑ

# DC ELECTRICAL CHARACTERISTICS (MC74VHC1GT08)

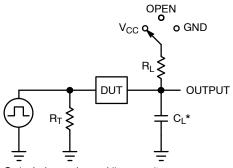
		Test	V <sub>CC</sub>	7	A = 25°	С	<b>-40°C</b> ≤ 1	Γ <sub>A</sub> ≤ 85°C	-55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		2.0	1.0	-	_	1.0	-	1.0	-	V
	Voltage		3.0	1.4	-	_	1.4	-	1.4	-	
			4.5	2.0	-	_	2.0	-	2.0	-	
			5.5	2.0	-	_	2.0	-	2.0	-	
V <sub>IL</sub>	Low-Level Input		2.0	_	-	0.28	-	0.28	-	0.28	V
	Voltage		3.0	_	-	0.45	-	0.45	-	0.45	
			4.5	-	-	0.8	-	0.8	-	0.8	
			5.5	-	-	0.8	-	0.8	-	0.8	
V <sub>OH</sub>	High-Level Output Voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -50  \mu\text{A} \\ &I_{OH} = -4  m\text{A} \\ &I_{OH} = -8  m\text{A} \end{aligned}$	2.0 3.0 4.5 3.0 4.5	1.9 2.9 4.4 2.58 3.94	2.0 3.0 4.5 -		1.9 2.9 4.4 2.48 3.80		1.9 2.9 4.4 2.34 3.66	- - - -	>
V <sub>OL</sub>	Low-Level Output Voltage	$\begin{array}{c} V_{IN} = V_{IH} \text{ or } V_{IL} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 50  \mu\text{A} \\ I_{OL} = 4 \text{ mA} \\ I_{OL} = 8 \text{ mA} \end{array}$	2.0 3.0 4.5 3.0 4.5	- - - -	0.0 0.0 0.0 - -	0.1 0.1 0.1 0.36 0.36	- - - -	0.1 0.1 0.1 0.44 0.44	- - - -	0.1 0.1 0.1 0.52 0.52	V
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	_	-	±0.1	-	±1.0	-	±1.0	μΑ
l <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	_	-	1.0	-	10	-	10	μΑ
Icc	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	_	-	1.0	-	20	-	40	μΑ
Ісст	Increase in Quies- cent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5	-	-	1.35	-	1.5	-	1.65	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### **AC ELECTRICAL CHARACTERISTICS**

				T <sub>A</sub> = 25°C -		T <sub>A</sub> = 25°C		$T_A \le 85^{\circ}C$ $-55^{\circ}C \le T_A \le 1$		A ≤ 125°C	
Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation Delay,	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	4.1	8.8	-	10.5	-	12.5	ns
t <sub>PHL</sub>	A to Y (Figures 3 and 4)	C <sub>L</sub> = 50 pF		_	5.9	12.3	-	14.0	-	16.5	
		C <sub>L</sub> = 15 pF	4.5 to 5.5	-	3.5	5.9	-	7.0	-	9.0	
		C <sub>L</sub> = 50 pF		_	4.2	7.9	-	9.0	-	11.0	
C <sub>IN</sub>	Input Capacitance			-	4.0	10	-	10	-	10	pF
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State		-	6.0	-	-	-	-	-	pF
Symbol	Parameter							Typical (	@ 25°C, V <sub>C</sub>	c = 5.0 V	Unit
C <sub>PD</sub>	Power Dissipation Ca	pacitance (Not	e 5)						8.0		pF

<sup>5.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.



Test	Switch Position	C <sub>L</sub> , pF	$R_L, \Omega$
t <sub>PLH</sub> / t <sub>PHL</sub>	Open	See AC Characteristics Table	Х
t <sub>PLZ</sub> / t <sub>PZL</sub>	V <sub>CC</sub>		1 k
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND		1 k

X = Don't Care

 $C_L$  includes probe and jig capacitance  $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega)$  f = 1 MHz

Figure 3. Test Circuit

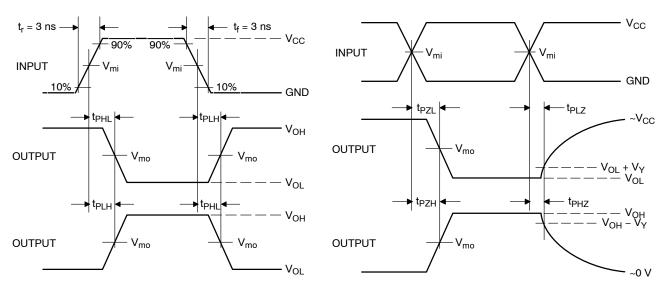


Figure 4. Switching Waveforms

		V <sub>mo</sub> , V		
V <sub>CC</sub> , V	V <sub>mi</sub> , V	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PZL}$ , $t_{PLZ}$ , $t_{PZH}$ , $t_{PHZ}$	V <sub>Y</sub> , V
3.0 to 3.6	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3
4.5 to 5.5	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	0.3

# **ORDERING INFORMATION**

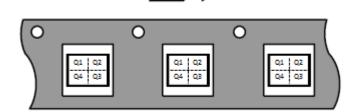
Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC1G08DFT1G	SC-88A	V2	Q2	3000 / Tape & Reel
MC74VHC1G08DFT2G	SC-88A	V2	Q4	3000 / Tape & Reel
MC74VHC1G08DFT1G-Q*	SC-88A	V2	Q2	3000 / Tape & Reel
MC74VHC1G08DFT2G-Q*	SC-88A	V2	Q4	3000 / Tape & Reel
MC74VHC1GT08DFT1G	SC-88A	VT	Q2	3000 / Tape & Reel
MC74VHC1GT08DFT2G	SC-88A	VT	Q4	3000 / Tape & Reel
MC74VHC1GT08DFT1G-Q*	SC-88A	VT	Q2	3000 / Tape & Reel
MC74VHC1GT08DFT2G-Q*	SC-88A	VT	Q4	3000 / Tape & Reel
MC74VHC1G08DBVT1G	SC-74A	V2	Q4	3000 / Tape & Reel
MC74VHC1G08DBVT1G-Q*	SC-74A	V2	Q4	3000 / Tape & Reel
MC74VHC1GT08DBVT1G	SC-74A	VT	Q4	3000 / Tape & Reel
MC74VHC1GT08DBVT1G-Q*	SC-74A	VT	Q4	3000 / Tape & Reel
MC74VHC1G08P5T5G	SOT-953	E	Q2	8000 / Tape & Reel
MC74VHC1GT08P5T5G	SOT-953	Р	Q2	8000 / Tape & Reel
MC74VHC1G08MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	K (Rotated 180° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT08MU1TCG	UDFN6, 1.45 x 1.0, 0.5P	4 (Rotated 270° CW)	Q4	3000 / Tape & Reel
MC74VHC1G08MU2TCG	UDFN6, 1.2 x 1.0, 0.4P	2	Q4	3000 / Tape & Reel
MC74VHC1G08MU3TCG	UDFN6, 1.0 x 1.0, 0.35	D (Rotated 270° CW)	Q4	3000 / Tape & Reel
MC74VHC1GT08MU3TCG	UDFN6, 1.0 x 1.0, 0.35	K	Q4	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*-Q Suffix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

# **PIN 1 ORIENTATION IN TAPE AND REEL**

# Direction of Feed



Capable.

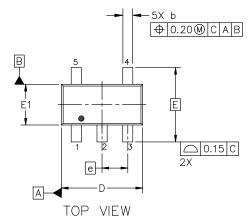


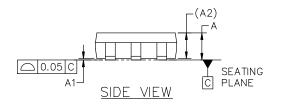
PACKAGE DIMENSIONS

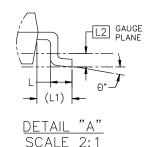


### SC-74A-5 3.00x1.50x0.95, 0.95P CASE 318BQ **ISSUE C**

**DATE 26 FEB 2024** 







### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code M

= Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.

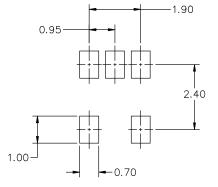
### NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME 1. Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

DETAII	_ A —
END	VIEW

DIM			
DIIVI	MIN.	NOM.	MAX.
Α	0.90	1.00	1.10
A1	0.01	0.18	0.10
A2	(	0.95 REF	
b	0.25	0.37	0.50
С	0.10	0.18	0.26
D	2.85	3.00	3.15
E	:	2.75 BSC	;
E1	1.35	1.50	1.65
е	0.95 BSC		
L	0.20	0.40	0.60
L1	0.62 REF.		
L2	0.25 BSC		
Θ	0,	5*	10°

**MILLIMETERS** 



### RECOMMENDED MOUNTING FOOTPRINT\*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

DOCUMENT NUMBER:	Electronic versions are uncontrolled except when accessed directly from the Document R Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SC-74A-5 3.00x1.50x0.95, 0.95P		PAGE 1 OF 1

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PACKAGE DIMENSIONS



### SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

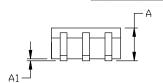
**DATE 11 APR 2023** 

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE. NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

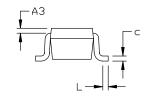
DIM	MILLIMETERS		
INITU	MIN.	N□M.	MAX.
А	0.80	0.95	1.10
A1			0.10
A3		0.20 REF	•
b	0.10	0.20	0.30
C	0.10		0.25
D	1.80	2.00	2,20
Е	2.00	2.10	2.20
E1	1.15	1.25	1.35
е	0.65 BSC		
L	0.10	0.15	0.30

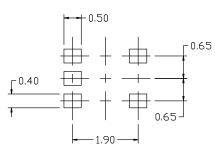
# e Ε1 0



5X b

◆ 0.2 M B M





#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **GENERIC MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:
PIN 1. BASE
<ol><li>EMITTER</li></ol>
3. BASE
<ol><li>COLLECTOR</li></ol>
<ol><li>COLLECTOR</li></ol>

STYLE 6:

STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR CATHODE

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 STYLE 8:

STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3 SOURCE 1 4. GATE 1 5. GATE 2

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE

3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

PIN 1	. EMITTER 2
2	BASE 2
3	. EMITTER 1
4	COLLECTOR
5	. COLLECTOR 2/BASE 1

STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR

PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER

PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5 ANODE

STYLE 9:

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

# **DOCUMENT NUMBER:**

98ASB42984B

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**DESCRIPTION:** 

SC-88A (SC-70-5/SOT-353)

PAGE 1 OF 1

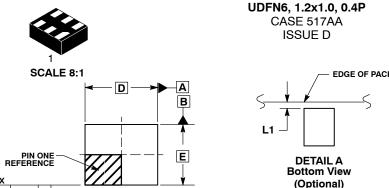
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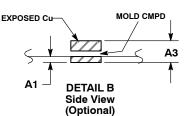
0.10 C

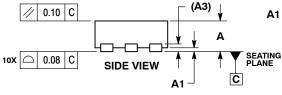
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# **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS

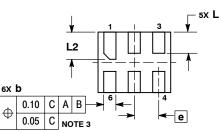


EDGE OF PACKAGE





**TOP VIEW** 



**BOTTOM VIEW** 

#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL.

  COPLANARITY APPLIES TO THE EXPOSED

**DATE 03 SEP 2010** 

PAD AS WELL AS THE TERMINALS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.127	REF	
b	0.15	0.25	
D	1.20 BSC		
E	1.00 BSC		
е	0.40 BSC		
L	0.30	0.40	
L1	0.00	0.15	
L2	0.40	0.50	

### **GENERIC** MARKING DIAGRAM\*

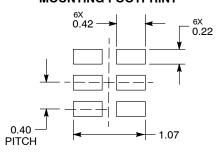


= Specific Device Code Χ Μ = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■",

# **MOUNTING FOOTPRINT\***

may or may not be present.



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON22068D Electronic versions are uncontrolled except when accessed directly from the Doct Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in		
DESCRIPTION:	6 PIN UDFN, 1.2X1.0, 0.4P		PAGE 1 OF 1

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6X 🗀

0.05 C

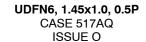
# **MECHANICAL CASE OUTLINE**

NOTES:
1. DIMENSIONING AND TOLERANCING PER

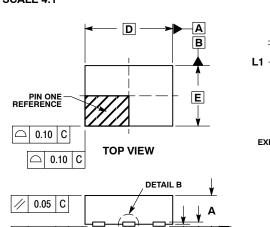
MILLIMETERS

ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

# PACKAGE DIMENSIONS



**DATE 15 MAY 2008** 



SIDE VIEW

е

**A**1

**A2** 

6X b

Ф

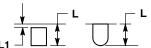
0.10

CAB

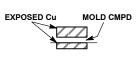
0.05 C NOTE 3

6X L

C SEATING PLANE



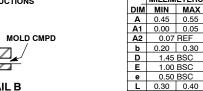
**DETAIL A** OPTIONAL CONSTRUCTIONS



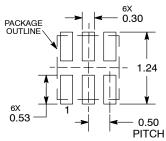
OPTIONAL

CONSTRUCTIONS

**DETAIL B** 



# **MOUNTING FOOTPRINT**



**DIMENSIONS: MILLIMETERS** 

# **GENERIC MARKING DIAGRAM\***

**BOTTOM VIEW** 

XM

Χ = Specific Device Code

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DESCRIPTION:	UDFN6, 1.45x1.0, 0.5P		PAGE 1 OF 1

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<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

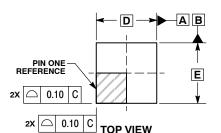


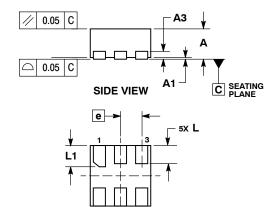
PACKAGE DIMENSIONS



UDFN6, 1x1, 0.35P CASE 517BX **ISSUE O** 

**DATE 18 MAY 2011** 





0.10 M C A B

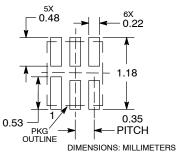
0.05 M C NOTE 3

#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP. 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13	REF	
b	0.12	0.22	
D	1.00 BSC		
E	1.00 BSC		
е	0.35 BSC		
L	0.25	0.35	
L1	0.30	0.40	

#### RECOMMENDED **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **GENERIC MARKING DIAGRAM\***

**BOTTOM VIEW** 



X = Specific Device Code

M = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	UDFN6, 1x1, 0.35P		PAGE 1 OF 1

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MILLIMETERS

 $N\square M$ 

0.37

0.15

0.12

MIN

0.34

0.10

0.07

DIM

Α

b

C





### SOT-953 1.00x0.80x0.37, 0.35P CASE 527AE **ISSUE F**

**DATE 17 JAN 2024** 

MAX

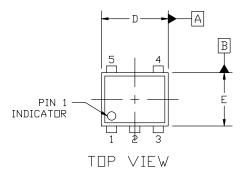
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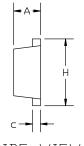
0.20

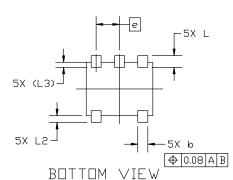
0.17

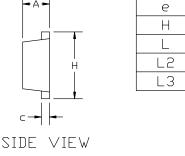
#### NOTES:

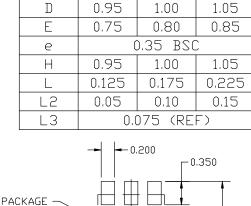
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

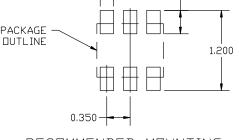












# RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

# **GENERIC MARKING DIAGRAM\***



= Specific Device Code

= Month Code

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	SOT-953 1.00x0.80x0.37, 0.35P		PAGE 1 OF 1

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